

Features

- ◆ Transient protection for data lines to **IEC 61000-4-2 (ESD) ±15kV (air), ±12kV (contact)**
IEC 61000-4-4 (EFT) 40A (tp = 5/50ns)
Cable Discharge Event (CDE)
- ◆ Ultra-small package (1.0 x 0.6 x 0.5mm)
- ◆ Protects one data or I/O line
- ◆ Low capacitance: **0.5pF(max)**
- ◆ Low clamping voltage
- ◆ Low operating voltage: 12V
- ◆ Solid-state silicon-avalanche technology

Mechanical Characteristics

- ◆ Package: DFN1006-2
- ◆ Lead Finish: Matte Tin
- ◆ UL Flammability Classification Rating 94V-0
- ◆ Pb-Free, Halogen Free, RoHS/WEEE Compliant



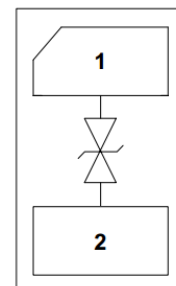
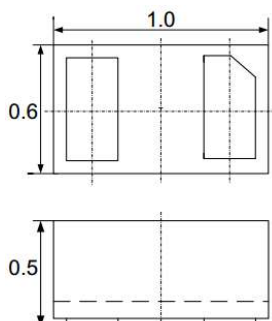
Applications

- ◆ Cellular Handsets & Accessories
- ◆ Digital Visual Interface (DVI)
- ◆ Display Port
- ◆ MDDI Ports
- ◆ USB Ports
- ◆ PCI Express
- ◆ Serial ATA

Ordering Information

Part Number	Qty per Reel	Reel Size
TPESD1221P	3000 Or 10000	7"

Circuit Diagram and Pin Configuration

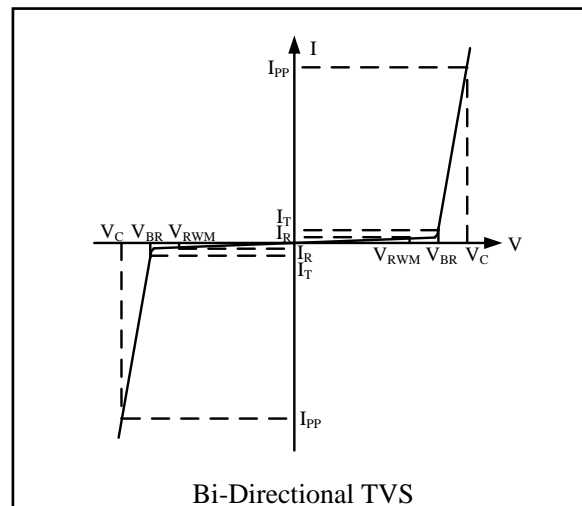


Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Limits	unit
IEC61000-4-2(ESD) Contact Air	V_{ESD}	± 15 ± 12	KV
Operating Temperature	T_{OPT}	-55/+125	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55/+150	$^\circ\text{C}$

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter
V_{RWM}	Nominal Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Reverse Breakdown Voltage @ I_T
I_T	Test Current for Reverse Breakdown
V_C	Clamping Voltage @ I_{PP}
I_{PP}	Maximum Peak Pulse Current
C_{ESD}	Parasitic Capacitance
V_R	Reverse Voltage
f	Small Signal Frequency



Symbol	Test Condition	Minimum	Typical	Maximum	Units
V_{RWM}				12.0	V
I_R	$V_{RWM} = 12\text{V}$, $T = 25^\circ\text{C}$ Between I/O and I/O		0.01	1.0	μA
V_{BR}	$I_T = 1\text{mA}$ Between I/O and I/O	14	16	18	V
V_C	$I_{PP} = 1\text{A}$, $t_p = 8/20\mu\text{s}$ Between I/O and I/O		18	20	V
C_{ESD}	$V_R = 0\text{V}$, $f = 1\text{MHz}$ Between I/O and I/O		0.35	0.50	pF

PROTECTION PRODUCTS
Typical characteristics

Fig1. 8/20 μ s Pulse Waveform

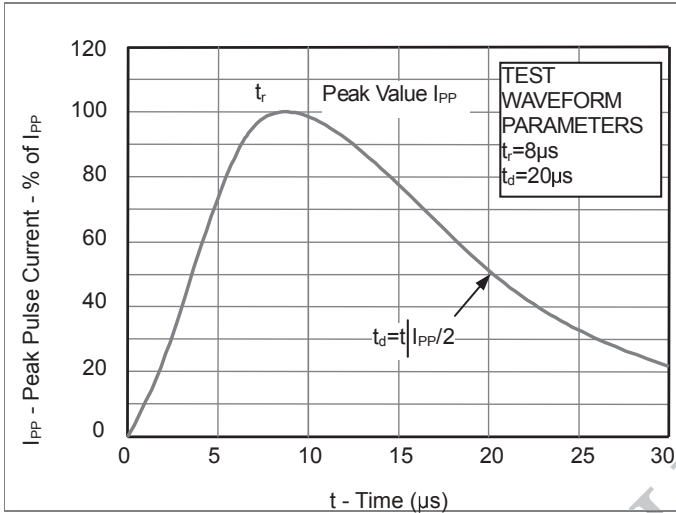


Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)

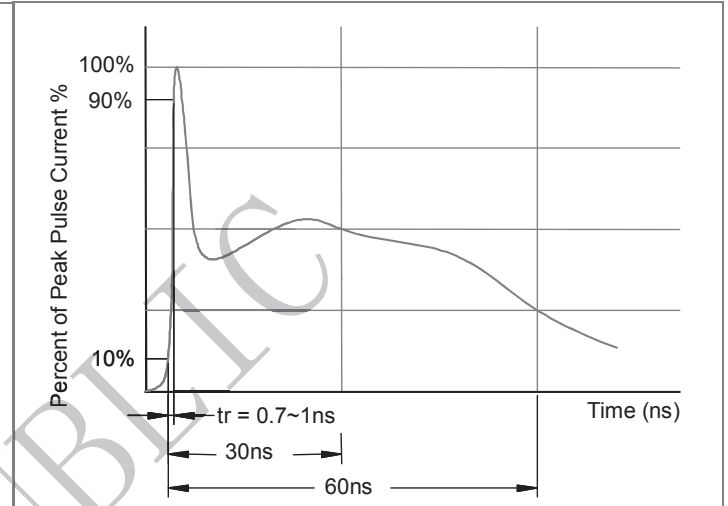
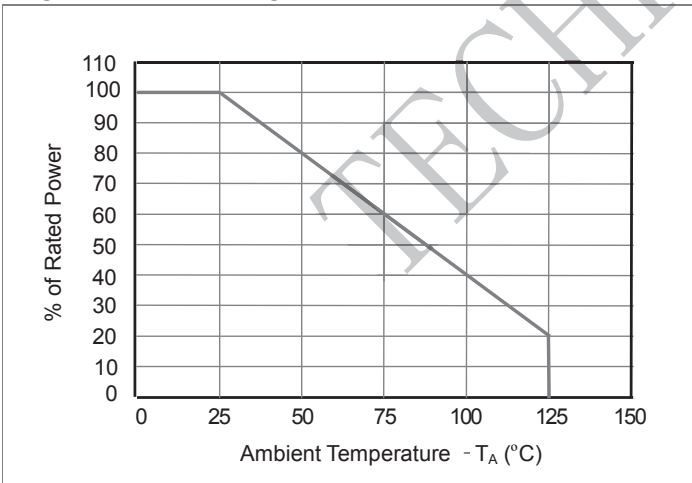
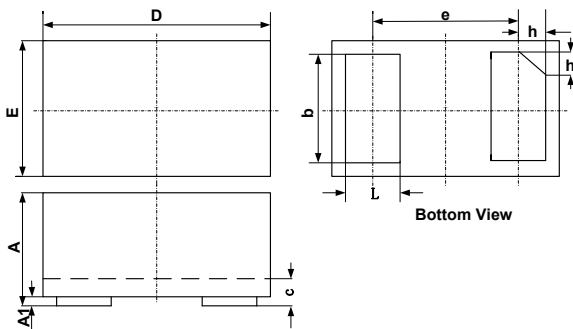


Fig3. Power Derating Curve

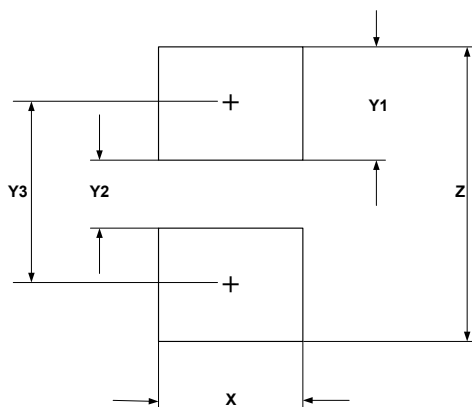


Outline Drawing - DFN1006-2



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
c	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
h	0.07	0.12	0.17	0.003	0.005	0.007

Land Pattern - DFN1006-2



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
X	0.60	0.024
Y1	0.50	0.020
Y2	0.30	0.012
Y3	0.80	0.032
Z	1.30	0.052

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [ESD Suppressors / TVS Diodes](#) category:

Click to view products by [TECH PUBLIC](#) manufacturer:

Other Similar products are found below :

[NTE4902](#) [P4SMAJ15A](#) [P4SMAJ26A](#) [SMAJ400CA-TP](#) [TGL34-47CA](#) [ESDAULC45-1BF4](#) [SM1605E3/TR13](#) [SMF20A-TP](#) [P4SMAJ12A](#)
[CPDUR24V-HF](#) [CPDQC5V0USP-HF](#) [CPDQC5V0-HF](#) [MPLAD30KP45CAE3](#) [MMBZ27VCLQ-7-F](#) [MMAD1108/TR13](#) [MPLAD30KP24A](#)
[ACPDQC5V0R-HF](#) [DFLT170A-7](#) [NTE4900](#) [NTE4926](#) [NTE4938](#) [SMF22A-TP](#) [SMF12A-TP](#) [SLVU2.8-TP](#) [SMLJ6.5CA-TP](#) [SMAJ6.5CA-](#)
[TP](#) [MMAD1108E3/TR13](#) [D5V0M1U2LP3-7](#) [SMAJ400A-TP](#) [AOZ8811DT-03](#) [AOZ8831DI-05](#) [AOZ8831DT-03](#) [SMAJ188CA](#) [3SMC33CA](#)
[BK](#) [CPDQC3V3C-HF](#) [CPDQC12VE-HF](#) [MPLAD30KP170CA](#) [82357120100](#) [5.0SMLJ15CA-TP](#) [5KP18A-TP](#) [P6KE8.2A-TP](#)
[MPLAD30KP43CAE3](#) [SMAJ43A-TP](#) [D5V0F6U8LP33-7](#) [TVS5501V10MUT5G](#) [5.0SMLJ24CA-TP](#) [SMAJ110CA-TP](#) [MPLAD15KP75CAE3](#)
[MMAD1103e3/TR13](#) [DFLT40AQ-7](#)